



●特点：■击穿电压稳定■开关速度快■安全工作区宽■符合ROHS规范

●FEATURES: ■HIGH VOLTAGE CAPABILITY ■HIGH SPEED SWITCHING ■WIDE SOA ■ROHS COMPLIANT

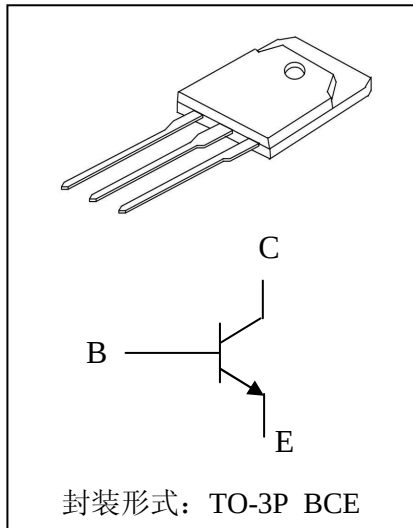
●应用■PC电源■节能灯■电子镇流器■电子变压器等开关电路

●APPLICATION: ■FLUORESCENT LAMP ■ELECTRONIC BALLAST ■ELECTRONIC TRANSFORMER ECT.

●最大额定值 (TC=25℃)

●Absolute Maximum Ratings (Tc=25℃)

| 参数名称<br>PARAMETER                      | 符号<br>SYMBOL | 额定值<br>VALUE | 单位<br>UNIT |
|----------------------------------------|--------------|--------------|------------|
| 集电极-基极电压<br>Collector-Base Voltage     | VCBO         | 700          | V          |
| 集电极-发射极电压<br>Collector-Emitter Voltage | VCEO         | 410          | V          |
| 发射极-基极<br>Emitter-Base Voltage         | VEBO         | 9            | V          |
| 集电极电流<br>Collector Current             | Ic           | 12           | A          |
| 集电极耗散功率<br>Total Power Dissipation     | PC           | 120          | W          |
| 最高工作温度<br>Junction Temperature         | Tj           | 150          | ℃          |
| 贮存温度<br>Storage Temperature            | TsTg         | -55-150      | ℃          |



电特性 (TC=25℃)

Electrical Characteristics (Tc=25℃)

| 参数名称<br>CHARACTERISTICS                             | 符号<br>SYMBOL | 测试条件<br>TEST CONDITION        | 最小值<br>MIN | 最大值<br>MAX | 单位<br>UNIT |
|-----------------------------------------------------|--------------|-------------------------------|------------|------------|------------|
| 集电极-基极截止电流<br>Collector-Base Cutoff Current         | ICBO         | VCB=700V                      |            | 5          | uA         |
| 集电极-发射极截止电流<br>Collector-Emitter Cutoff Current     | ICEO         | VCE=400V, IB=0                |            | 10         | uA         |
| 集电极-发射极电压<br>Collector-Emitter Voltage              | VCEO         | IC=10mA, IB=0                 | 410        |            | V          |
| 发射极-基极电压<br>Collector-Base Voltage                  | VEBO         | IE=1mA, IC=0                  | 9          |            | V          |
| 集电极-发射极饱和压降<br>Collector-Emitter Saturation Voltage | Vcesat       | IC=5.0A, IB=1.0A              |            | 0.30       |            |
|                                                     |              | IC=8.0A, IB=2.0A              |            | 0.65       | V          |
|                                                     |              | IC=12A, IB=4.0A               |            | 0.85       | V          |
| 发射极-基极饱和压降<br>Base-Emitter Saturation Voltage       | Vbesat       | IC=8.0A, IB=2.0A              |            | 1.2        | V          |
| 电流放大倍数<br>DC Current Gain                           | Hfe          | VCE=5V, IC=1mA                | 8          |            |            |
|                                                     |              | VCE=5V, IC=5.0A               | 20         | 35         |            |
|                                                     |              | VCE=5V, IC=12A                | 6          |            |            |
| 贮存时间<br>Storage Time                                | ts           | VCC=5V<br>IC=0.5A<br>(UI9600) | 4.0        | 10.0       | us         |
| 下降时间<br>falling time                                | tf           |                               |            | 0.8        |            |

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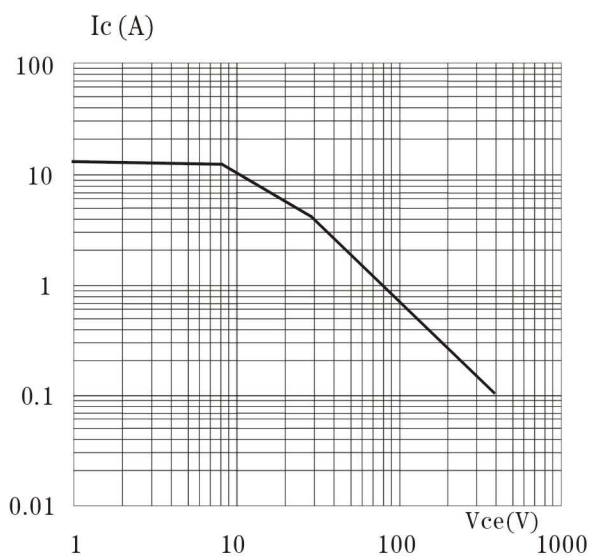
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SOA(DC)



$P_c \propto T_j$

